## 1. General description

P-channel enhancement mode MOSFET in an LFPAK56 (Power SO8) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.
This product has been designed and qualified to AEC-Q101 standard for use in high-performance automotive applications such as reverse battery protection.

## 2. Features and benefits

- High thermal power dissipation capability
- Suitable for thermally demanding environments due to $175^{\circ} \mathrm{C}$ rating
- Trench MOSFET technology
- AEC-Q101 qualified


## 3. Applications

- Reverse battery protection
- Power management
- High-side loadswitch
- Motor drive


## 4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions |  | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\mathrm{DS}}$ | drain-source voltage | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | - | - | -60 | V |
| $\mathrm{~V}_{\mathrm{GS}}$ | gate-source voltage |  | $[1]$ | -20 | - | 20 | V |
| $\mathrm{I}_{\mathrm{D}}$ | drain current | $\mathrm{V}_{\mathrm{GS}}=-10 \mathrm{~V} ; \mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$ |  | - | - | -23 | A |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation | $\mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$ |  | - | - | 66 | W |

Static characteristics

| $R_{D S O n}$ | drain-source on-state <br> resistance | $V_{G S}=-10 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=-4.8 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | - | 45 | 57 | $\mathrm{~m} \Omega$ |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |

[1] $\mathrm{V}_{\mathrm{GS}}=-20 \mathrm{~V} /+5 \mathrm{~V}$ according $\mathrm{AEC}-\mathrm{Q} 101$ at $\mathrm{T}_{\mathrm{j}}=175^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{GS}}=-20 \mathrm{~V} /+20 \mathrm{~V}$ according AEC-Q101 at $\mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| :---: | :---: | :---: | :---: | :---: |
| 1 | S | source | LFPAK56; PowerSO8 (SOT669) | $017 a a a 094$ |
| 2 | S | source |  |  |
| 3 | S | source |  |  |
| 4 | G | gate |  |  |
| mb | D | mounting base; connected to drain |  |  |

## 6. Ordering information

Table 3. Ordering information

| Type number | Package | Vescription | Version |
| :--- | :--- | :--- | :--- |
|  | Name | Descred | SOT669 |
| BUK6Y57-60P | LFPAK56; <br> Power-SO8 | plastic, single-ended surface-mounted package; 4 terminals |  |

## 7. Marking

Table 4. Marking codes

| Type number | Marking code |
| :--- | :--- |
| BUK6Y57-60P | 6 Y 5760 P |

## 8. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions |  | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {DS }}$ | drain-source voltage | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | - | -60 | V |
| $V_{G S}$ | gate-source voltage |  | [1] | -20 | 20 | V |
| $\mathrm{I}_{\mathrm{D}}$ | drain current | $\mathrm{V}_{\mathrm{GS}}=-10 \mathrm{~V} ; \mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$ |  | - | -23 | A |
|  |  | $\mathrm{V}_{\mathrm{GS}}=-10 \mathrm{~V} ; \mathrm{T}_{\mathrm{mb}}=100^{\circ} \mathrm{C}$ |  | - | -16 | A |
| $\mathrm{I}_{\mathrm{DM}}$ | peak drain current | single pulse; $\mathrm{t}_{\mathrm{p}} \leq 10 \mu \mathrm{~s} ; \mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$ |  | - | -91 | A |
| $P_{\text {tot }}$ | total power dissipation | $\mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$ |  | - | 66 | W |
| $\mathrm{T}_{\mathrm{j}}$ | junction temperature |  |  | -55 | 175 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {amb }}$ | ambient temperature |  |  | -55 | 175 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  |  | -65 | 175 | ${ }^{\circ} \mathrm{C}$ |
| Source-drain diode |  |  |  |  |  |  |
| $I_{s}$ | source current | $\mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$ |  | - | -23 | A |
| $\mathrm{I}_{\text {SM }}$ | peak source current | single pulse; $\mathrm{t}_{\mathrm{p}} \leq 10 \mu \mathrm{~s} ; \mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$ |  | - | -91 | A |
| ESD maximum rating |  |  |  |  |  |  |
| $V_{\text {ESD }}$ | electrostatic discharge voltage | HBM | [2] | - | 1000 | V |
| Avalanche ruggedness |  |  |  |  |  |  |
| $\mathrm{E}_{\mathrm{DS}(\mathrm{AL}) \mathrm{S}}$ | non-repetitive drainsource avalanche energy | $\mathrm{V}_{\text {sup }} \leq-60 \mathrm{~V} ; \mathrm{V}_{G S}=-10 \mathrm{~V} ; \mathrm{T}_{\mathrm{j} \text { (init) }}=25^{\circ} \mathrm{C}$; $\mathrm{I}_{\mathrm{D}}=-4.8 \mathrm{~A}$; DUT in avalanche (unclamped) |  | - | 3.9 | mJ |

[1] $\mathrm{V}_{\mathrm{GS}}=-20 \mathrm{~V} /+5 \mathrm{~V}$ according AEC-Q101 at $\mathrm{T}_{\mathrm{j}}=175^{\circ} \mathrm{C}$; $\mathrm{V}_{\mathrm{GS}}=-20 \mathrm{~V} /+20 \mathrm{~V}$ according $\mathrm{AEC}-\mathrm{Q} 101$ at $\mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$
[2] Measured between all pins.


Fig. 1. Normalized total power dissipation as a function of junction temperature


Fig. 2. Normalized continuous drain current as a function of junction temperature


Fig. 3. Safe operating area; junction to mounting base; continuous and peak drain currents as a function of drain-source voltage

## 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions |  | Min | Typ | Max |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $R_{\text {th(j-mb) }}$ | thermal resistance <br> from junction to <br> mounting base |  | - | 1.8 | 2.3 | K/W |



Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

## 10. Characteristics

Table 7. Characteristics
$T_{j}=25^{\circ} \mathrm{C}$ unless otherwise specified

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Static characteristics |  |  |  |  |  |  |
| $\mathrm{V}_{\text {(BR) }{ }^{\text {dSS }}}$ | drain-source breakdown voltage | $\mathrm{I}_{\mathrm{D}}=-250 \mu \mathrm{~A} ; \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$ | -60 | - | - | V |
| $\mathrm{V}_{\text {GSth }}$ | gate-source threshold voltage | $\mathrm{I}_{\mathrm{D}}=-250 \mu \mathrm{~A} ; \mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{G S} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | -1.5 | -2 | -3 | V |
| $\mathrm{I}_{\text {DSS }}$ | drain leakage current | $V_{\text {DS }}=-60 \mathrm{~V} ; \mathrm{V}_{G S}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | - | -1 | $\mu \mathrm{A}$ |
|  |  | $V_{D S}=-60 \mathrm{~V} ; \mathrm{V}_{G S}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=175{ }^{\circ} \mathrm{C}$ | - | - | -100 | $\mu \mathrm{A}$ |
| IGSS | gate leakage current | $V_{G S}=20 \mathrm{~V} ; \mathrm{V}_{\text {DS }}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | - | 100 | nA |
|  |  | $V_{G S}=-20 \mathrm{~V} ; \mathrm{V}_{\text {DS }}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | - | -100 | nA |
| $\mathrm{R}_{\text {DSon }}$ | drain-source on-state resistance | $V_{G S}=-10 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=-4.8 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 45 | 57 | $m \Omega$ |
|  |  | $V_{G S}=-10 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=-4.8 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=175^{\circ} \mathrm{C}$ | - | 100 | 127 | $m \Omega$ |
|  |  | $V_{G S}=-4.5 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=-3.9 \mathrm{~A}$ | - | 58 | 87 | $\mathrm{m} \Omega$ |
| $\mathrm{gfs}_{\text {f }}$ | forward transconductance | $V_{D S}=-10 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=-2 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 65 | - | S |
| $\mathrm{R}_{\mathrm{G}}$ | gate resistance | $\mathrm{f}=1 \mathrm{MHz}$ | - | 7 | - | $\Omega$ |
| Dynamic characteristics |  |  |  |  |  |  |
| $\mathrm{Q}_{\mathrm{G} \text { (tot) }}$ | total gate charge | $V_{D S}=-30 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=-5.3 \mathrm{~A} ; \mathrm{V}_{G S}=-10 \mathrm{~V}$ | - | 21 | 24 | nC |
| $Q_{G S}$ | gate-source charge |  | - | 3.7 | - | nC |
| $Q_{G D}$ | gate-drain charge |  | - | 4.6 | - | nC |
| $\mathrm{C}_{\text {iss }}$ | input capacitance | $V_{D S}=-30 \mathrm{~V} ; \mathrm{f}=1 \mathrm{MHz} ; \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$ | - | 1200 | - | pF |
| $\mathrm{C}_{\text {oss }}$ | output capacitance |  | - | 105 | - | pF |
| $\mathrm{C}_{\text {rss }}$ | reverse transfer capacitance |  | - | 56 | - | pF |
| $\mathrm{t}_{\mathrm{d} \text { (on) }}$ | turn-on delay time | $\begin{aligned} & V_{D S}=-30 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=-4.8 \mathrm{~A} ; \mathrm{V}_{\mathrm{GS}}=-10 \mathrm{~V} ; \\ & \mathrm{R}_{\mathrm{G}(\text { ext })}=6 \Omega \end{aligned}$ | - | 6 | - | ns |
| $\mathrm{t}_{\mathrm{r}}$ | rise time |  | - | 12 | - | ns |
| $\mathrm{t}_{\mathrm{d} \text { (off) }}$ | turn-off delay time |  | - | 39 | - | ns |
| $\mathrm{t}_{\mathrm{f}}$ | fall time |  | - | 16 | - | ns |
| Source-drain diode |  |  |  |  |  |  |
| $V_{\text {SD }}$ | source-drain voltage | $\mathrm{I}_{\mathrm{S}}=-22.7 \mathrm{~A} ; \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | -0.7 | -1.2 | V |
| $\mathrm{t}_{\mathrm{rr}}$ | reverse recovery time | $\begin{aligned} & \mathrm{I}_{\mathrm{S}}=-4.8 \mathrm{~A} ; \mathrm{dl}_{\mathrm{S}} / \mathrm{dt}=100 \mathrm{~A} / \mu \mathrm{s} ; \\ & \mathrm{V}_{G S}=0 \mathrm{~V} ; \mathrm{V}_{\mathrm{DS}}=-30 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \end{aligned}$ | - | 30 | - | ns |
| $Q_{r}$ | recovered charge |  | - | 36 | - | nC |



Fig. 5. Output characteristics: drain current as a function of drain-source voltage; typical values

$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$
Fig. 7. Drain-source on-state resistance as a function of drain current; typical values

$V_{D S}=-5 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$
Fig. 6. Sub-threshold drain current as a function of gate-source voltage

$I_{D}=-5 A$
Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values


Fig. 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$I_{D}=-250 \mu A ; V_{D S}=V_{G S}$
Fig. 11. Gate-source threshold voltage as a function of junction temperature


Fig. 10. Normalized drain-source on-state resistance as a function of junction temperature; typical values


Fig. 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values


Fig. 13. Gate-source voltage as a function of gate charge; typical values

$\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$
Fig. 15. Source current as a function of source-drain voltage; typical values

## 11. Test information



Fig. 16. Duty cycle definition

## Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## 12. Package outline

Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads

$0^{\circ}$
Dimensions (mm are the original dimensions)


Fig. 17. Package outline LFPAK56; Power-SO8 (SOT669)

## 13. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
| :--- | :--- | :--- | :--- | :--- |
| BUK6Y57-60P v.3 | 20180705 | Product data sheet | - | BUK6Y57-60P v.2 |
| Modifications: | - Characteristics: Fig. 5 updated. |  |  |  |
| BUK6Y57-60P v.2 | 20180606 | Product data sheet | - | BUK6Y57-60P v.1 |
| BUK6Y57-60P v.1 | 20180309 | Product data sheet | - | - |

## 14. Legal information

## Data sheet status

| Document status <br> [1][2] | Product <br> status [3] | Definition |
| :--- | :--- | :--- |
| Objective [short] <br> data sheet | Development | This document contains data from <br> the objective specification for <br> product development. |
| Preliminary [short] <br> data sheet | Qualification | This document contains data from <br> the preliminary specification. |
| Product [short] <br> data sheet | Production | This document contains the product <br> specification. |

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
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